

自主封測 品質把控 售後保障

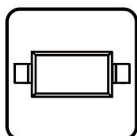
WEB | WWW.TDSEMIC.COM



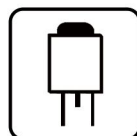
電源管理



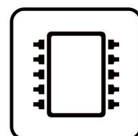
顯示驅動



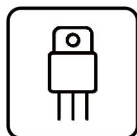
二三極管



LDO穩壓器



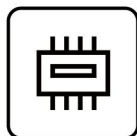
觸摸芯片



MOS管



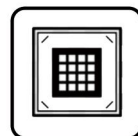
運算放大器



存儲芯片



MCU



串口通信

85HF100-TD

產品規格說明書

Standard Recovery Diodes, (Stud Version), 85 A

85HF(R)



DO-5 (DO-203AB)

FEATURES

- High surge current capability
- Stud cathode and stud anode version
- Leaded version available
- Types up to 1600 V V_{RRM}
- Designed and qualified for industrial level



RoHS
COMPLIANT

TYPICAL APPLICATIONS

- Battery chargers
- Converters
- Power supplies
- Machine tool controls
- Welding

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	85 A
Package	DO-5 (DO-203AB)
Circuit configuration	China

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	85HF(R)		UNITS
		10 to 120	140 to 160	
$I_{F(AV)}$	T_C	85	85	A
		140	110	°C
$I_{F(RMS)}$		133	133	A
I_{FSM}	50 Hz	1700	1700	A
	60 Hz	1800	1800	
I^2t	50 Hz	14 500	14 500	A ² s
	60 Hz	13 500	13 500	
V_{RRM}	Range	100 to 1200	1400 to 1600	V
T_J		-65 to +180	-65 to +150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
85HF(R)	10	100	200	9
	20	200	300	
	40	400	500	
	60	600	700	
	80	800	900	
	100	1000	1100	
	120	1200	1300	
	140	1400	1500	4.5
	160	1600	1700	

FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			85HF(R)		UNITS
					10 to 120	140/160	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			85		A
					140	110	°C
Maximum RMS forward current	I _{F(RMS)}				133		A
Maximum peak, one-cycle forward, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = T _J maximum	1700		A
		t = 8.3 ms			1800		
		t = 10 ms	100 % V _{RRM} reapplied		1450		
		t = 8.3 ms			1500		
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		14 500		A ² s
		t = 8.3 ms			13 500		
		t = 10 ms	100 % V _{RRM} reapplied		10 500		
		t = 8.3 ms			9400		
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			16 000		A ² √s
Value of threshold voltage (up to 1200 V)	V _{F(TO)}	T _J = T _J maximum			0.68		V
Value of threshold voltage (for 1400 V, 1600 V)					0.69		
Value of forward slope resistance (up to 1200 V)	r _f	T _J = T _J maximum			1.62		mW
Value of forward slope resistance (for 1400 V, 1600 V)					1.75		
Maximum forward voltage drop	V _{FM}	I _{pk} = 267 A, T _J = 25 °C, t _p = 400 μs rectangular wave			1.2	1.4	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	85HF(R)		UNITS
			10 to 20	140 to 160	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-65 to +180	-65 to +150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.35		K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		
Maximum shock ⁽¹⁾			1500		g
Maximum constant vibration ⁽¹⁾		50 Hz	20		
Maximum constant acceleration ⁽¹⁾		Stud outwards	5000		
Maximum allowable mounting torque + 0 %, - 10 %		Not lubricated thread, tightening on nut	3.4 (30)		N · m (lbf · in)
		Lubricated thread, tightening on nut	2.3 (20)		
		Not lubricated thread, tightening on hexagon	4.2 (37)		
		Lubricated thread, tightening on hexagon	3.2 (28)		
Approximate weight		Unleaded device	17		g
			0.6		oz.
Case style		See dimensions - link at the end of datasheet	DO-5 (DO-203AB)		

Notes

- ⁽¹⁾ Available only for 88HF
- ⁽²⁾ Recommended for pass-through holes
- ⁽³⁾ Recommended for holed threaded heatsinks

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.10	0.08	$T_J = T_J$ maximum	K/W
120°	0.11	0.11		
90°	0.13	0.13		
60°	0.17	0.17		
30°	0.26	0.26		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

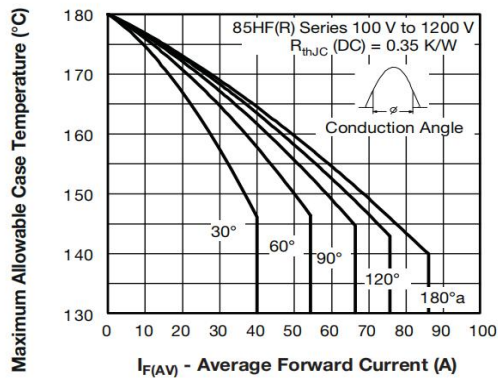


Fig. 1 - Current Ratings Characteristics

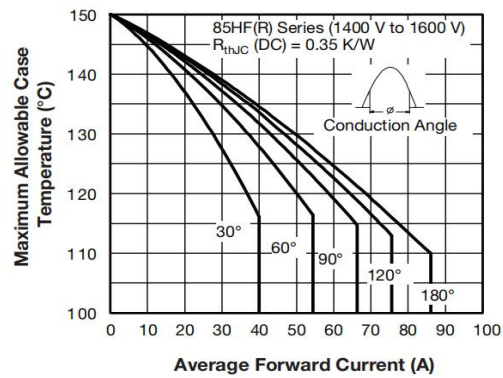


Fig. 3 - Current Ratings Characteristics

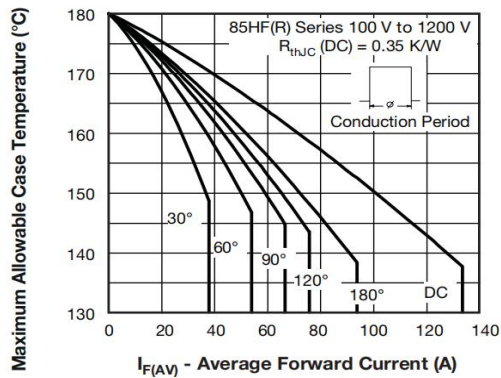


Fig. 2 - Current Ratings Characteristics

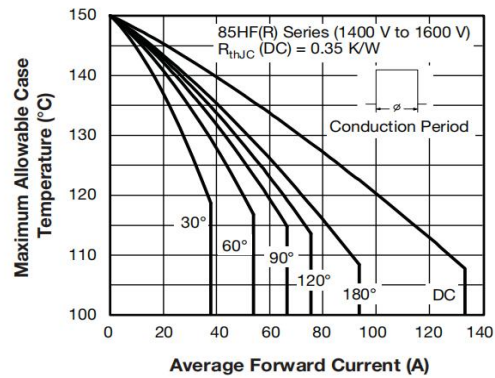


Fig. 4 - Current Ratings Characteristics

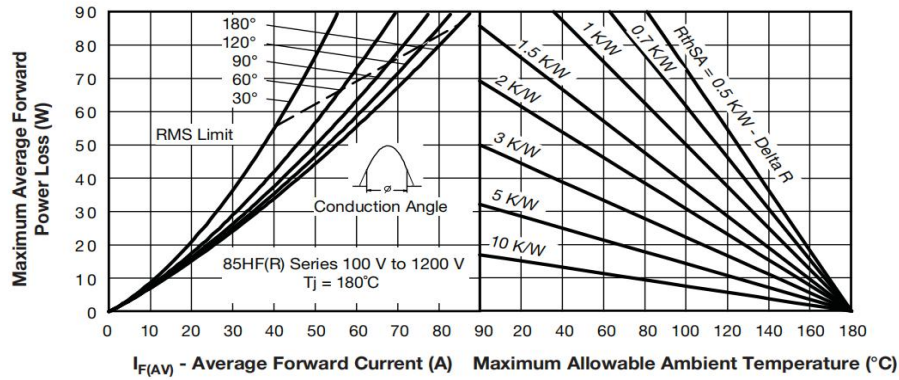


Fig. 5 - Forward Power Loss Characteristics

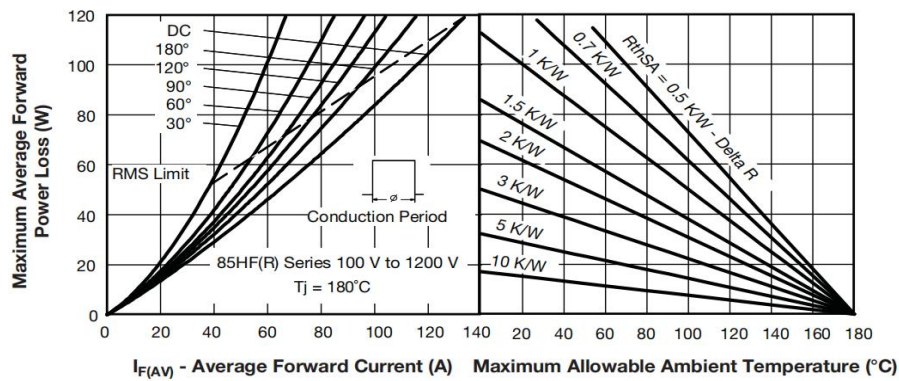


Fig. 6 - Forward Power Loss Characteristics

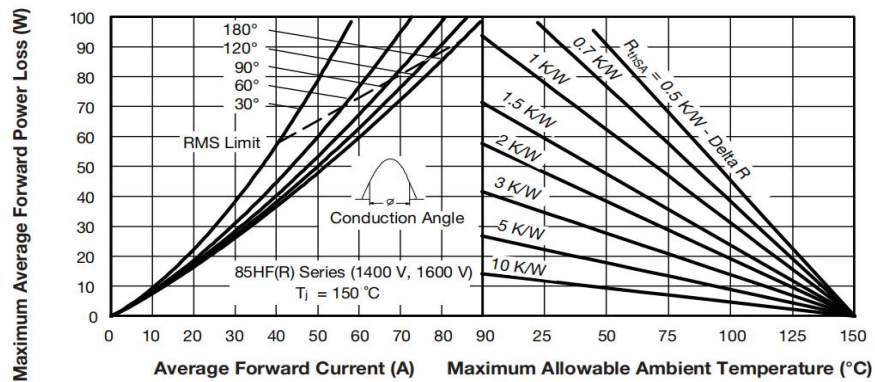


Fig. 7 - Forward Power Loss Characteristics

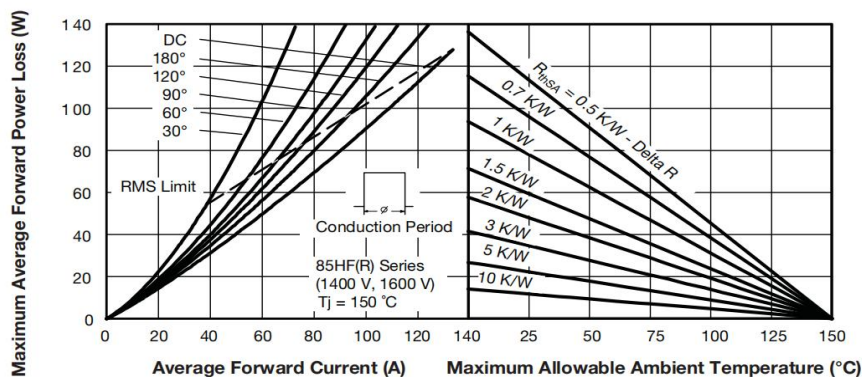


Fig. 8 - Forward Power Loss Characteristics

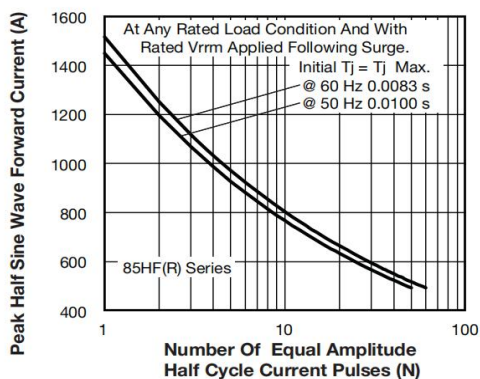


Fig. 9 - Maximum Non-Repetitive Surge Current

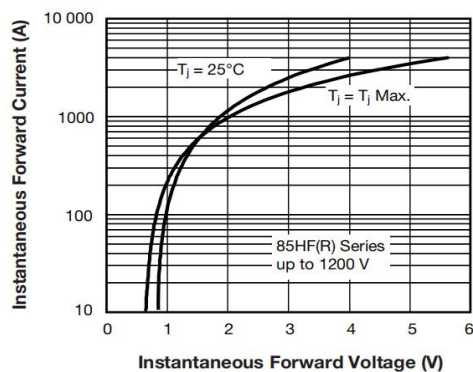


Fig. 11 - Forward Voltage Drop Characteristics

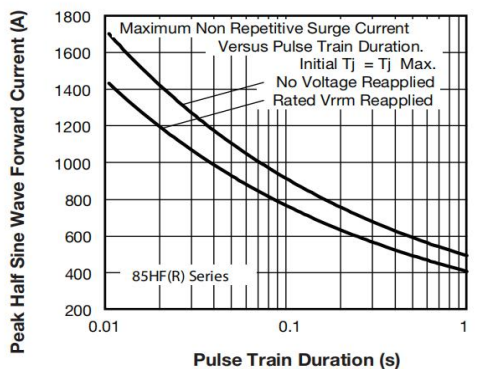


Fig. 10 - Maximum Non-Repetitive Surge Current

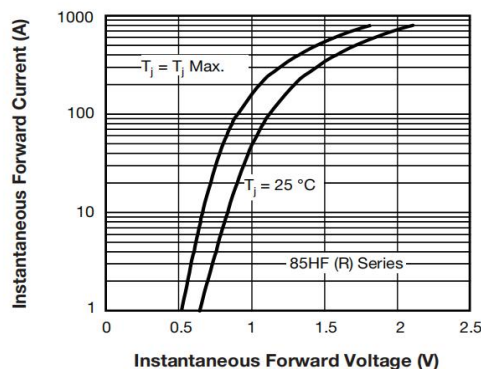


Fig. 12 - Forward Voltage Drop Characteristics
(for 1400 V, 1600 V)

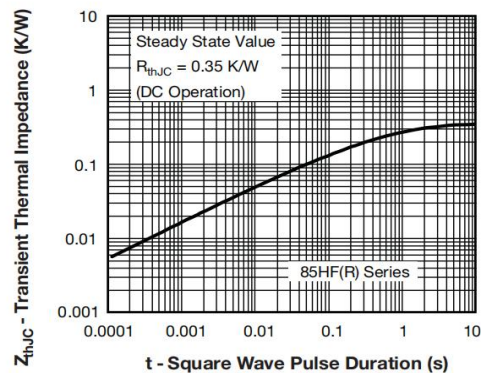
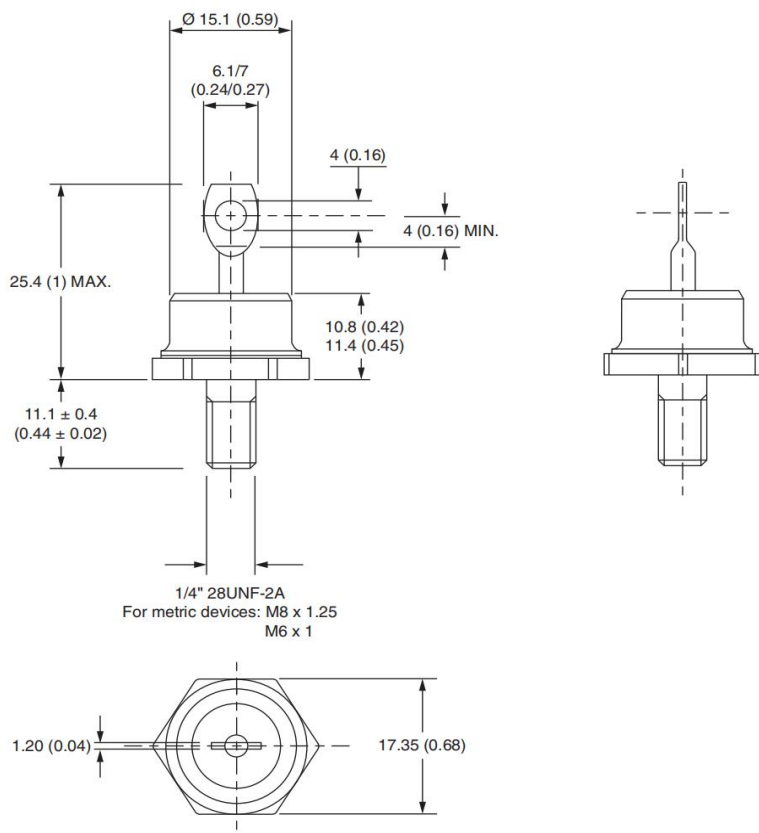


Fig. 13 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	85	HF	R	160	M
	1	2	3	4	5
1	- 85 = standard device				
2	- 86 = not isolated lead				
	- 87 = isolated lead with silicone sleeve				
	(red = Reverse polarity)				
	(blue = Normal polarity)				
	- 88 = type for rotating application				
3	- None = stud normal polarity (cathode to stud)				
4	- R = stud reverse polarity (anode to stud)				
	- Voltage code x 10 = V_{RRM} (see Voltage Ratings table)				
5	- None = stud base DO-5 (DO-203AB) 1/4" 28UNF-2A				
	- M = stud base DO-5 (DO-203AB) M6 x 1 (not available for 88HF)				
	- M8 = stud base DO-5 (DO-203AB) M8 x 1.25 (not available for 88HF)				

DO-5 (DO-203AB) for 85HF(R)



DO-5 (DO-203AB) for 85HF(R)

